NSN 5961-00-884-1646

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-884-1646 **Inclosure Material:** Glass and metal **Overall Length:** 4.000 inches **Overall Diameter:** 0.750 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 52.0 forward voltage, average **Current Rating Per Characteristic:** 1.00 amperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 49671-2185678 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No